



D15V0S1U2LP1610Q

ONE CHANNEL HIGH SURGE TVS DIODE

Product Summary

VBR (Min)	PP (Max)	Ст (Тур)
17.0V	44A	270pF

Description

This new generation TVS is designed to protect sensitive electronics from the damage due to ESD. The combination of small size and high ESD surge capability makes it ideal for protecting one line against high surge current and other transients.

Applications

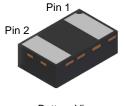
- Power line protections
- Mobile device applications
- Touch panels
- Small panel modules
- Type-C "CC"
- V_{DD} protections

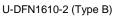
Features

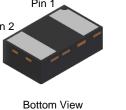
- Provides ESD Protection per IEC 61000-4-2 Standard: Air ±30kV. Contact ±30kV
- One Channel of ESD Protection
- Low Channel Input Capacitance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3) The DIODES™ D15V0S1U2LP1610Q is suitable for
- automotive applications requiring specific change control; this part is AEC-Q101 gualified, PPAP capable, and manufactured in IATF 16949 certified facilities. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: U-DFN1610-2
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: NiPdAu. Solderable per MIL-STD-202, Method 208 @4)
- Weight: 0.003 grams (Approximate)









Device Schematic

Ordering Information (Note 4)

Notes:

Part Number	Package	Marking Code	Reel Size	Tape Width	Packing		
Fait Nulliber	Fackage	Marking Code	(inches)	(mm)	Qty.	Carrier	
D15V0S1U2LP1610Q-7	U-DFN1610-2 (Type B)	15T	7	8	10,000	Tape & Reel	

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

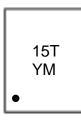
<1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Option A:



15T = Product Type Marking Code YM = Date Code Marking Y = Year (ex: J = 2022) M = Month (ex: 9 = September) Dot Denotes Cathode Side

Date Code Key

Year	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	J	K	L	М	N	0	Р	R	S	Т	U	V
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
monun	oun	100	initial	, Abi	initialy	oun	Vui	Aug	000	001	1101	000

Option B:

	15T YWX	
•		

15T = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 to 9) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code Dot Denotes Cathode Side

Year	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	2	3	4	5	6	7	8	9	0	1	2	3
Week		1-	26			27-	-52			5	3	
Code	A-Z			a-z				Z				
Internal Code	Sun	1	Mon		Tue	We	d	Thu		Fri		Sat
Code	Т		U		V	W		Х		Y		Z



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
ESD Protection – Contact Discharge	Vesd_contact	±30	kV	Standard IEC 61000-4-2
ESD Protection – Air Discharge	Vesd_air	±30	kV	Standard IEC 61000-4-2

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Power Dissipation (Note 5)		PD	300	mW
Thermal Resistance, Junction to Ambient	T _A = +25°C	R _{0JA}	417	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

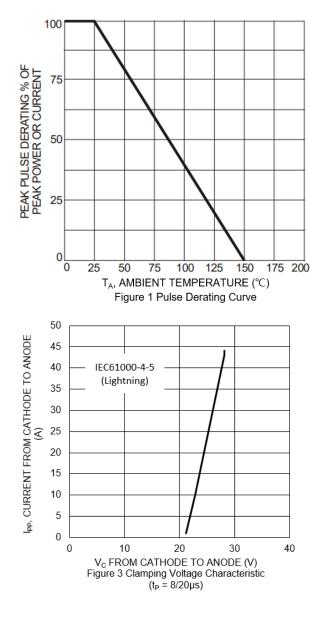
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

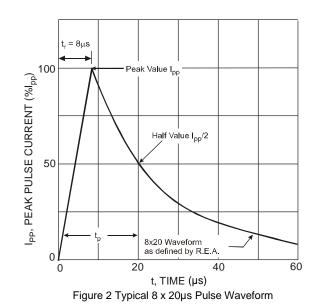
Part Number	Reverse Standoff Voltage	Breakdown Voltage Vвв. @ Іт		Test Current	Max. Reverse Leakage Current @ V _{RWM} (Note 6)	Max. Clamping Voltage @ IPP (Note 7)	Max. Peak Pulse Current	Channel Input Capacitance (Note 8) $V_R = 0V,$ f = 1MHz, Any I/O to GND	Marking Code
		VBR	@ I _T		(
	VRWM (V)	Min (V)	Max (V)	lτ (mA)	I _R (nA)	Vc (V)	IPP (A)	Ст (рF)	
D15V0S1U2LP1610Q-7	15	17	23	1	200	28	44	270	15T

5. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes Incorporated's suggested pad layout, which can be found on our website Notes: at http://www.diodes.com/package-outlines.html.
Short duration pulse test used to minimize self-heating effect.
Clamping voltage value is based on an 8x20µs peak pulse current (IPP) waveform.
Measured from any I/O to GND.



D15V0S1U2LP1610Q



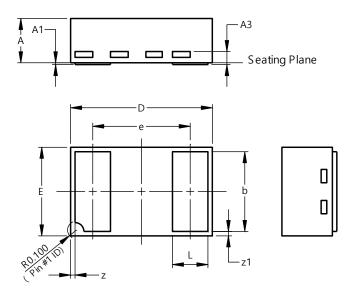




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN1610-2 (Type B)

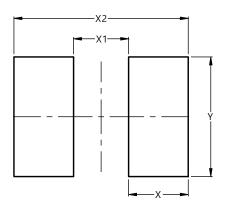


U-DFN1610-2 (Type B)								
Dim	Min Max 1							
Α	0.45	0.55	0.50					
A1	0.00	0.05	0.015					
A3	-	-	0.127					
b	0.85	0.95	0.90					
D	1.55	1.65	1.60					
E	0.95	1.05	1.00					
е	-	-	1.10					
L	0.35	0.45	0.40					
z	0.050 REF							
z1	0.050 REF							
All C	Dimens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN1610-2 (Type B)



Dimensions	Value (in mm)
Х	0.650
X1	0.600
X2	1.900
Y	1.300